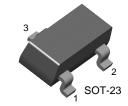


KST4123

General Purpose Transistor



1. Base 2. Emitter 3. Collector

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	40	V
V _{CEO}	Collector-Emitter Voltage	30	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current	200	mA
P _C	Collector Power Dissipation	350	mW
T _{STG}	Storage Temperature	150	°C
R _{TH} (j-a)	Thermal Resistance junction to Ambient	357	°C/W

Electrical Characteristics T_a =25°C unless otherwise noted

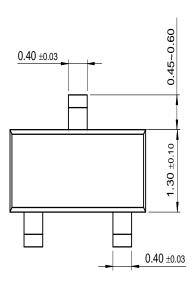
Symbol	Parameter	Test Condition	Min.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C =10μA, I _E =0	40		V
BV _{CEO}	* Collector-Emitter Breakdown Voltage	I _C =1mA, I _E =0	30		V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E =10μA, I _C =0	5		V
I _{CBO}	Collector Cut-off Current	V _{CB} =20V, I _E =0		50	nA
I _{EBO}	Emitter Cut-off Current	V _{EB} =3V, I _C =0		50	nA
h _{FE}	* DC Current Gain	V _{CE} =1V, I _C =2mA	50	150	
		V_{CE} =1V, I_{C} =50mA	25		
V _{CE} (sat)	* Collector-Emitter Saturation Voltage	I _C =50mA, I _B =5mA		0.3	V
V _{BE} (sat)	* Base-Emitter Saturation Voltage	I _C =50mA, I _B =5mA		0.95	V
f _T	Current Gain Bandwidth Product	V _{CE} =20V, I _C =10mA, f=100MHz	250		MHz
C _{ib}	Input Capacitance	V _{BE} =0.5V, I _C =0, f=100KHz		8	pF
C _{ob}	Output Capacitance	V _{CB} =5V, I _E =0, f=100KHz		4	pF
NF	Noise Figure	V_{CE} =5V, I_{C} =100 μ A, R_{S} =1 K Ω		6	dB
		Noise Bandwidth=10Hz to 15.7KHz			

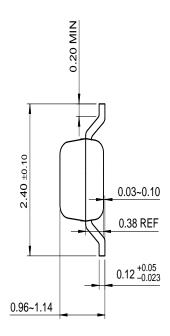
^{*} Pulse Test: PW≤300μs, Duty Cycle≤2%

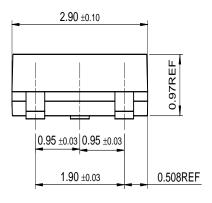


Package Dimensions

SOT-23







Dimensions in Millimeters

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EnSigna™	I^2C^{TM}	OCX^{TM}	RapidConfigure™	UHC™
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The Power Franchise™		OPTOLOGIC [®]	SILENT SWITCHER®	VCX^{TM}
Programmable Active Droop™		OPTOPLANAR™	SMART START™	

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